# BAT754L

# Schottky barrier triple diode

**22 November 2012** 

**Product data sheet** 

## 1. Product profile

#### 1.1 General description

Three internal isolated planar Schottky barrier diodes with an integrated guard ring for stress protection, encapsulated in very small SOT363 Surface-Mounted Device (SMD) plastic package.

#### 1.2 Features and benefits

- Low forward voltage
- Low capacitance
- AEC-Q101 qualified

### 1.3 Applications

- Ultra high-speed switching
- Line termination
- Voltage clamping
- Reverse polarity protection

#### 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Per diode	Per diode							
V <sub>R</sub>	reverse voltage			-	-	30	V	
Per diode					'		,	
V <sub>F</sub>	forward voltage	$I_F$ = 100 mA; pulsed; $t_p \le 300$ μs; $δ \le 0.02$ ; $T_{amb}$ = 25 °C		-	-	750	mV	
I <sub>R</sub>	reverse current	$V_R$ = 25 V; pulsed; $t_p \le 300 \text{ μs}$ ; $\delta \le 0.02$ ; $T_{amb}$ = 25 °C		-	-	2	μΑ	





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# 2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol	
1	A1	anode (diode 1)	<u>654</u>	K1 K2 K3	
2	A2	anode (diode 2)			
3	A3	anode (diode 3)	O	A1 A2 A aaa-00	
4	K3	cathode (diode 3)			aaa-005704
5	K2	cathode (diode 2)			
6	K1	cathode (diode 1)			

# 3. Ordering information

Table 3. Ordering information

Type number	Package	age				
	Name	Description	Version			
BAT754L	TSSOP6	plastic surface-mounted package; 6 leads	SOT363			

# 4. Marking

Table 4. Marking codes

Type number	Marking code
Typo Ildinisor	[1]
BAT754L	L1%

<sup>[1] % =</sup> placeholder for manufacturing site code

# 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit		
Per diode								
$V_R$	reverse voltage			-	30	V		
l <sub>F</sub>	forward current			-	200	mA		
I <sub>FRM</sub>	repetitive peak forward current	t <sub>p</sub> < 1 s; δ < 0.5		-	300	mA		
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ < 10 ms; $T_{j(init)}$ = 25 °C		-	600	mA		
T <sub>j</sub>	junction temperature			-	125	°C		
T <sub>amb</sub>	ambient temperature			-55	125	°C		

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### Schottky barrier triple diode

Symbol	Parameter	Conditions	Min	Max	Unit
T <sub>stg</sub>	storage temperature		-65	150	°C

## 6. Thermal characteristics

#### Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1]	-	-	416	K/W

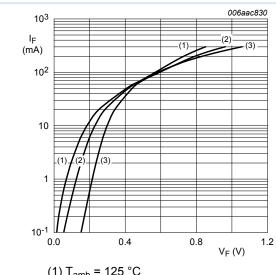
<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

# 7. Characteristics

**Table 7. Characteristics** 

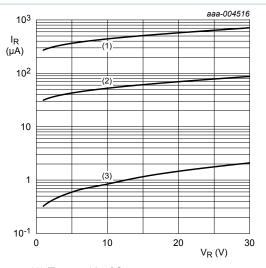
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						,
V <sub>F</sub> for	forward voltage	$I_F$ = 0.1 mA; pulsed; $t_p \le 300 \ \mu s$ ; δ ≤ 0.02 ; $T_{amb}$ = 25 °C	-	-	200	mV
		$I_F$ = 1 mA; pulsed; $t_p \le 300 \ \mu s$ ; $δ \le 0.02$ ; $T_{amb}$ = 25 °C	-	-	260	mV
		$I_F$ = 10 mA; pulsed; $t_p \le 300 \ \mu s$ ; $\delta \le 0.02$ ; $T_{amb}$ = 25 °C	-	-	340	mV
		$I_F$ = 30 mA; pulsed; $t_p \le$ 300 μs; $\delta \le$ 0.02 ; $T_{amb}$ = 25 °C	-	-	420	mV
		$I_F$ = 100 mA; pulsed; $t_p \le 300$ μs; $δ \le 0.02$ ; $T_{amb}$ = 25 °C	-	-	750	mV
I <sub>R</sub>	reverse current	$V_R$ = 25 V; pulsed; $t_p \le 300 \mu s$ ; $\delta \le 0.02$ ; $T_{amb}$ = 25 °C	-	-	2	μΑ
C <sub>d</sub>	diode capacitance	V <sub>R</sub> = 1 V; f = 1 MHz; T <sub>amb</sub> = 25 °C	-	-	10	pF

#### Schottky barrier triple diode



- (1)  $T_{amb} = 125 \, ^{\circ}C$
- (2)  $T_{amb}$  = 85 °C
- (3)  $T_{amb} = 25 \, ^{\circ}C$

Fig. 1. Forward current as a function of forward voltage; typical values



- (1)  $T_{amb} = 125 \, ^{\circ}C$
- (2)  $T_{amb}$  = 85 °C
- $(3) T_{amb} = 25 °C$

Fig. 2. Reverse current as a function of reverse voltage; typical values

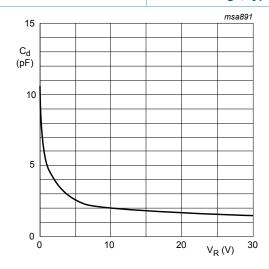


Fig. 3. Diode capacitance as a function of reverse voltage; typical values

#### **Test information** 8.

 $f = 1 MHz; T_{amb} = 25 °C$ 

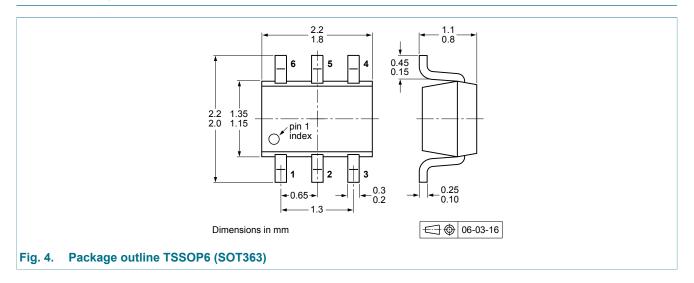
#### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

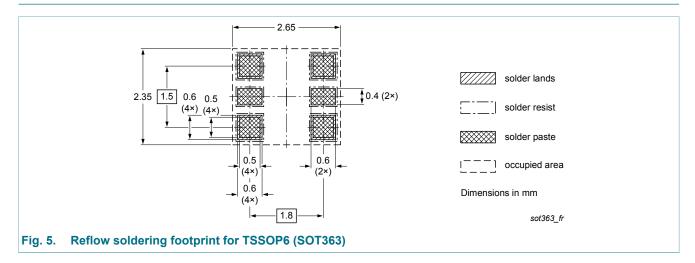
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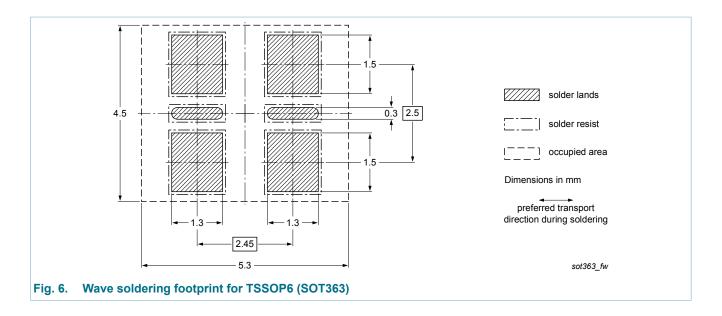
# 9. Package outline



# 10. Soldering



## Schottky barrier triple diode



# 11. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BAT754L v.2	20121122	Product data sheet	-	BAT754L v.1
Modifications:	of NXP Semiconduction Legal texts have be Section 1 Product pr	een adapted to the new co profile: updated updated ues: changed T <sub>amb</sub> minimal lated mation: added ed by minimized package ug: added	ompany name where app num value to -55°C acco	ropriate.
BAT754L v.1	20010118	Product specification	-	-

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#### Schottky barrier triple diode

## 12. Legal information

#### 12.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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